Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a 9 bumps Wafer Level Chip-Size Package (WLCSP) using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Ultra small package: 1.48 × 1.48 × 0.35 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V	
V _{GS}	gate-source voltage			-20	-	20	V	
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	6.1	A	
Static characte	Static characteristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 3 \text{ A}; T_j = 25 \text{ °C}$		-	28	41	mΩ	

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



60 V, N-channel Trench MOSFET

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
A1	G	gate	1 2 3	D
A2	S	source	$A \bigcirc \bigcirc \bigcirc$	
A3	S	source	В	G ← F 本 \
B1	S	source		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
B2	S	source		
В3	S	source	Transparent top view	s
C1	D	drain	WLCSP9 (WLCSP9_3x3)	017aaa255
C2	D	drain	_ ,	
C3	D	drain		

6. Ordering information

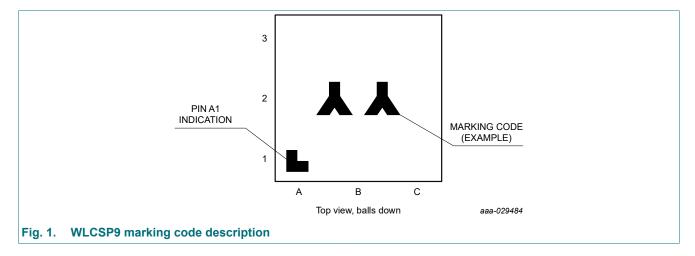
Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PMCM950ENE	WLCSP9	WLCSP9: wafer level chip-size package; 9 bumps (3 x 3)	WLCSP9_3x3			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMCM950ENE	A1



8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V_{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	6.1	А
		V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	4.8	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	3	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	19	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	780	mW
			[1]	-	1.4	W
		T _{sp} = 25 °C		-	12.5	W
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source Drain [Diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	1.4	А

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 2 .
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

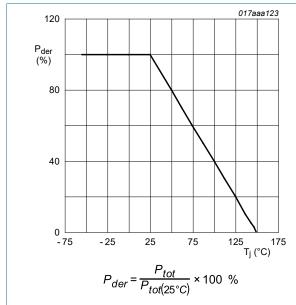


Fig. 2. Normalized total power dissipation as a function of junction temperature

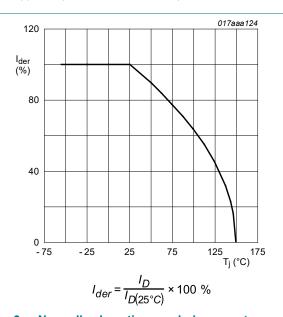


Fig. 3. Normalized continuous drain current as a function of junction temperature

60 V, N-channel Trench MOSFET

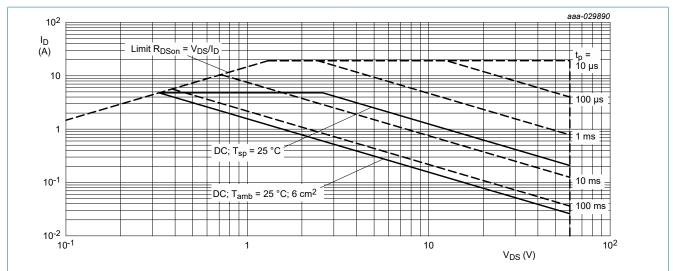


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from		[1]	-	130	160	K/W
	junction to ambient		[2]	-	50	60	K/W
			[3]	-	65	80	K/W
		t ≤ 5 s	[3]	-	42	50	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

- [1] Device mounted on an FR4 PCB, single sided-copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain, 4 layer, 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

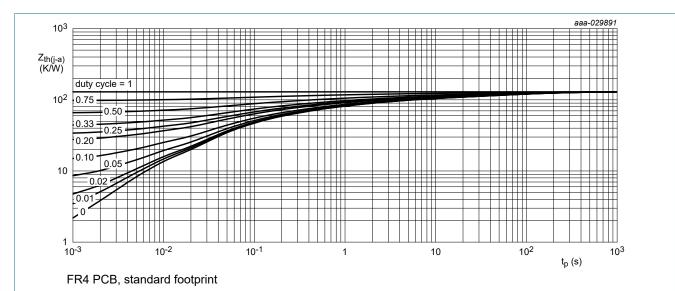


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

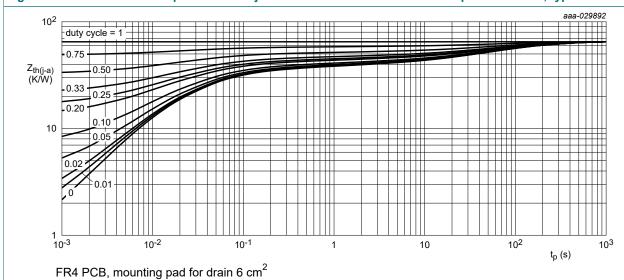


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	0.9	1.2	1.5	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μΑ
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μΑ
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	200	nA
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-200	nA
R_{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 3 A; T _j = 25 °C	-	28	41	mΩ
	resistance	V _{GS} = 10 V; I _D = 3 A; T _j = 150 °C	-	46	68	mΩ
		$V_{GS} = 4.5 \text{ V}; I_D = 3 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	31	47	mΩ
9 _{fs}	forward transconductance	$V_{DS} = 5 \text{ V}; I_D = 3 \text{ A}; T_j = 25 \text{ °C}$	-	20	-	S
R _G	gate resistance	f = 1 MHz	-	5.7	-	Ω
Dynamic ch	naracteristics			'		
Q _{G(tot)}	total gate charge	V _{DS} = 30 V; I _D = 3 A; V _{GS} = 10 V;	-	30	45	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.3	-	nC
Q _{GD}	gate-drain charge		-	5.9	-	nC
C _{iss}	input capacitance	V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V;	-	1160	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	71	-	pF
C _{rss}	reverse transfer capacitance		-	62	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 30 V; I _D = 3 A; V _{GS} = 10 V;	-	2	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4	-	ns
t _{d(off)}	turn-off delay time	1	-	70	-	ns
t _f	fall time		-	17	-	ns
Source-dra	in diode					
V_{SD}	source-drain voltage	I _S = 1.4 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

6 / 14

60 V, N-channel Trench MOSFET

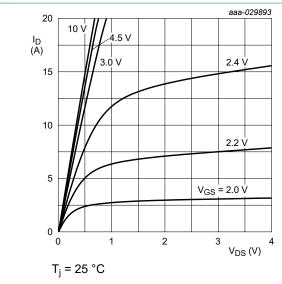


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

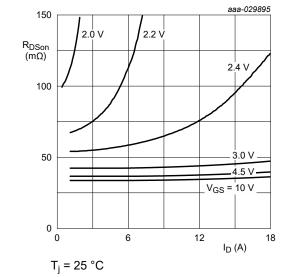


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

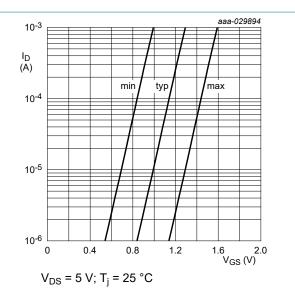


Fig. 8. Sub-threshold drain current as a function of gate-source voltage

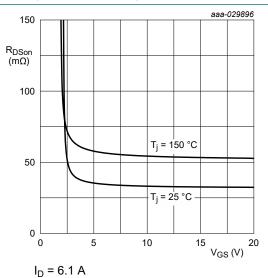


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

60 V, N-channel Trench MOSFET

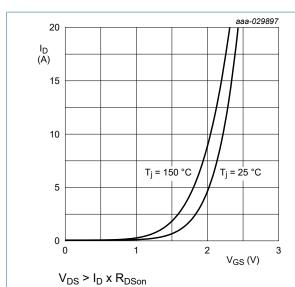


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

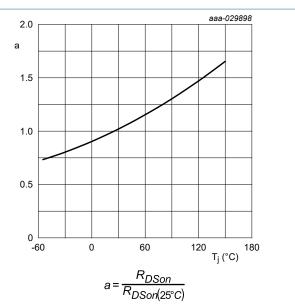


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

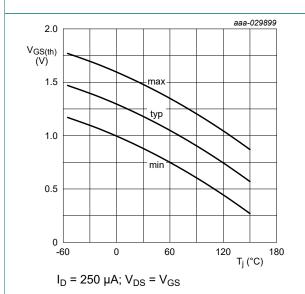
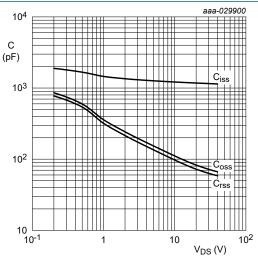


Fig. 13. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

60 V, N-channel Trench MOSFET

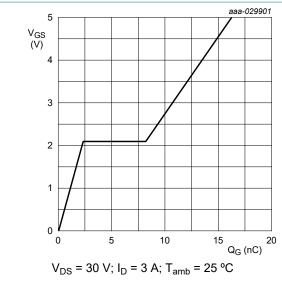


Fig. 15. Gate-source voltage as a function of gate charge; typical values

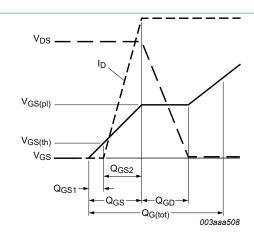


Fig. 16. Gate charge waveform definitions

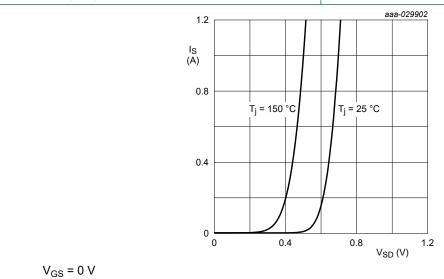
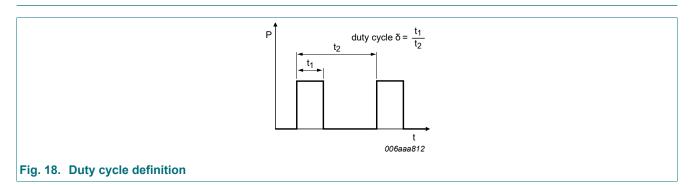


Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information



12. Package outline

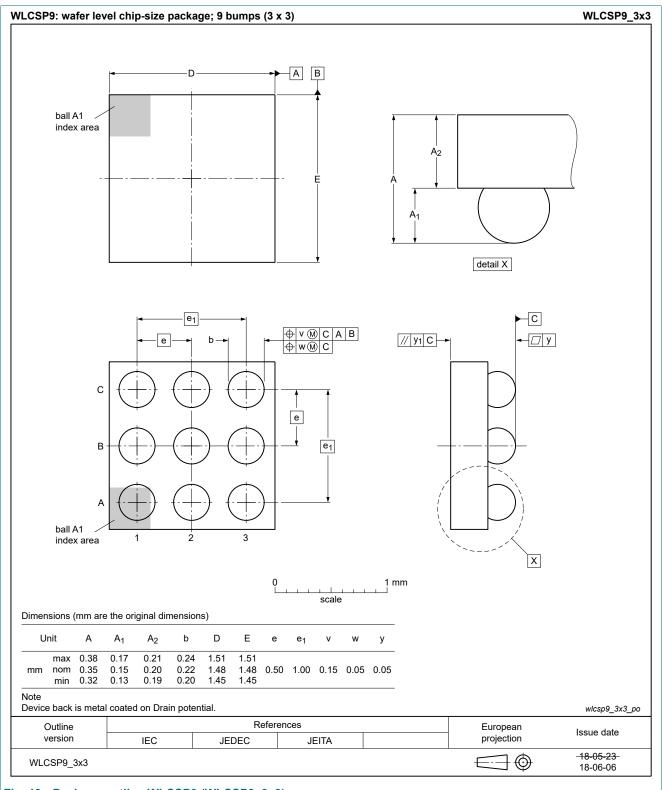
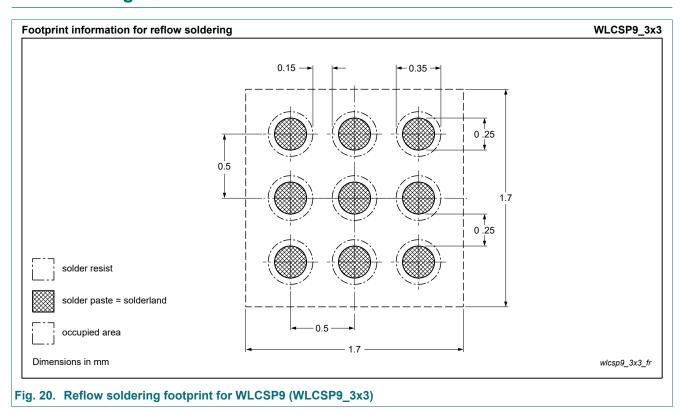


Fig. 19. Package outline WLCSP9 (WLCSP9_3x3)

60 V, N-channel Trench MOSFET

13. Soldering



60 V, N-channel Trench MOSFET

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMCM950ENE v.1	20190513	Product data sheet	-	-

60 V, N-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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PMCM950ENE

60 V, N-channel Trench MOSFET

Contents

General description	. 1
Features and benefits	1
Applications	1
Quick reference data	. 1
Pinning information	. 2
Ordering information	. 2
Marking	. 2
Limiting values	3
Thermal characteristics	5
Characteristics	. 6
Test information	. 9
Package outline1	10
Soldering 1	11
Revision history1	12
Legal information1	
	Features and benefits

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